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With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

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## **High Current Transistors**

### **PNP Silicon**

### **Features**

• Pb-Free Package is Available\*

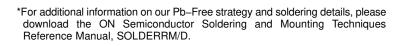
### **MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Collector - Emitter Voltage	V <sub>CEO</sub>	-60	Vdc
Collector - Base Voltage	V <sub>CBO</sub>	-60	Vdc
Emitter-Base Voltage	V <sub>EBO</sub>	-4.0	Vdc
Collector Current – Continuous	I <sub>C</sub>	-1.0	Adc
Total Device Dissipation @ T <sub>A</sub> = 25°C Derate above 25°C	P <sub>D</sub>	625 5.0	mW mW/°C
Total Device Dissipation  @ T <sub>C</sub> = 25°C  Derate above 25°C	P <sub>D</sub>	1.5 12	W mW/°C
Operating and Storage Junction Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

#### THERMAL CHARACTERISTICS

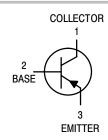
Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	200	°C/W
Thermal Resistance, Junction-to-Case	$R_{ heta JC}$	83.3	°C/W

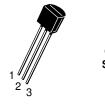




### ON Semiconductor®

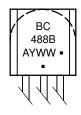
http://onsemi.com





TO-92 CASE 29 STYLE 17

#### **MARKING DIAGRAM**



BC488B = Device Code A = Assembly Location

Y = Year WW = Work Week ■ Pb-Free Package

(Note: Microdot may be in either location)

### **ORDERING INFORMATION**

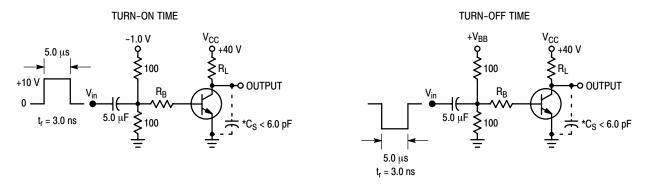
Device	Package	Shipping <sup>†</sup>
BC488BRL1	TO-92	2000/Tape & Reel
BC488BRL1G	TO-92 (Pb-Free)	2000/Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

## **ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$ unless otherwise noted)

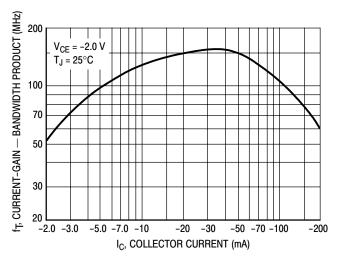
Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS		•			•
Collector – Emitter Breakdown Voltage (Note 1) $(I_C = -10 \text{ mAdc}, I_B = 0)$	V <sub>(BR)CEO</sub>	-60	_	_	Vdc
Collector – Base Breakdown Voltage $(I_C = -100 \mu Adc, I_E = 0)$	V <sub>(BR)CBO</sub>	-60	-	-	Vdc
Emitter – Base Breakdown Voltage $(I_E = -10 \mu Adc, I_C = 0)$	V <sub>(BR)EBO</sub>	-4.0	-	-	Vdc
Collector Cutoff Current $(V_{CB} = -40 \text{ Vdc}, I_E = 0)$	I <sub>CBO</sub>	-		-100	nAdc
ON CHARACTERISTICS*		•			•
DC Current Gain $ \begin{aligned} &(I_C = -10 \text{ mAdc},  V_{CE} = -2.0 \text{ Vdc}) \\ &(I_C = -100 \text{ mAdc},  V_{CE} = -2.0 \text{ Vdc}) \\ &(I_C = -1.0 \text{ Adc},  V_{CE} = -5.0 \text{ Vdc}) \end{aligned} $	h <sub>FE</sub>	40 160 15	_ 260 _	- 400 -	-
Collector – Emitter Saturation Voltage ( $I_C = -500 \text{ mAdc}$ , $I_B = -50 \text{ mAdc}$ ) ( $I_C = -1.0 \text{ Adc}$ , $I_B = -100 \text{ mAdc}$ )	V <sub>CE(sat)</sub>	_ _	-0.25 -0.5	-0.5 -	Vdc
Base – Emitter Saturation Voltage ( $I_C = -500$ mAdc, $I_B = -50$ mAdc) ( $I_C = -1.0$ Adc, $I_B = -100$ mAdc)	V <sub>BE</sub> (sat)	- -	-0.9 -1.0	-1.2 -	Vdc
DYNAMIC CHARACTERISTICS	·				
Current-Gain - Bandwidth Product (I <sub>C</sub> = -50 mAdc, V <sub>CE</sub> = -2.0 Vdc, f = 100 MHz)	f <sub>T</sub>	-	150	_	MHz
Output Capacitance $(V_{CB} = -10 \text{ Vdc}, I_E = 0, f = 1.0 \text{ MHz})$	C <sub>ob</sub>	-	9.0	_	pF
Input Capacitance (V <sub>EB</sub> = -0.5 Vdc, I <sub>C</sub> = 0, f = 1.0 MHz)	C <sub>ib</sub>	-	110	-	pF

<sup>1.</sup> Pulse Test: Pulse Width = 300 μs, Duty Cycle 2%.



<sup>\*</sup>Total Shunt Capacitance of Test Jig and Connectors For PNP Test Circuits, Reverse All Voltage Polarities

Figure 1. Switching Time Test Circuits



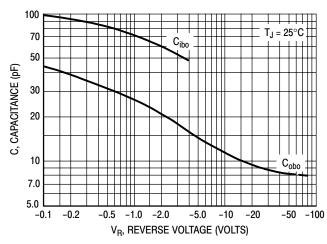


Figure 2. Current-Gain - Bandwidth Product

Figure 3. Capacitance

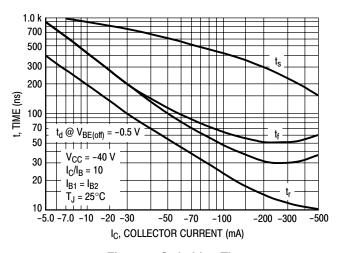


Figure 4. Switching Time

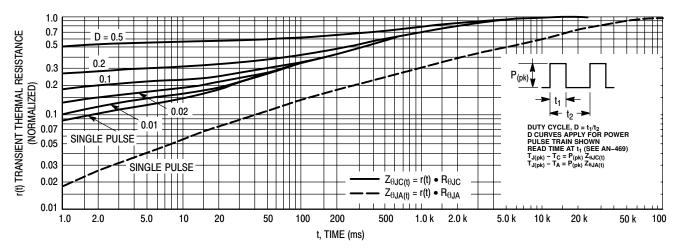


Figure 5. Thermal Response

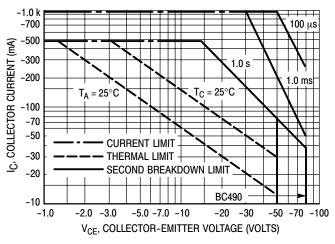


Figure 6. Active Region, Safe Operating Area

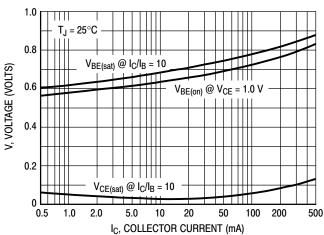


Figure 7. "On" Voltages

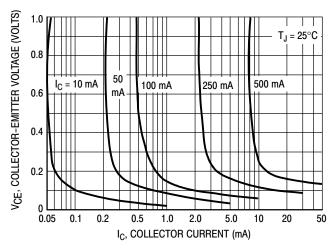


Figure 8. Collector Saturation Region

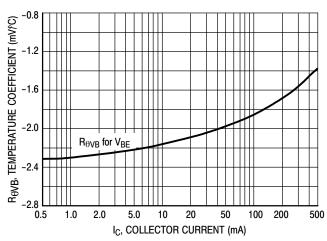


Figure 9. Base-Emitter Temperature Coefficient

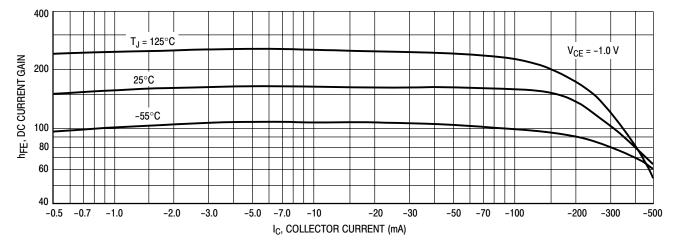
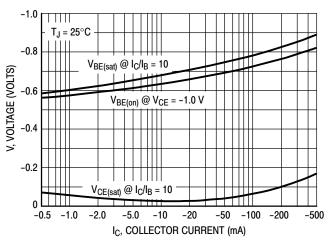


Figure 10. DC Current Gain



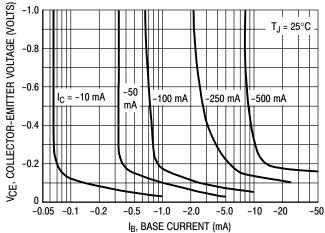


Figure 11. "On" Voltages

Figure 12. Collector Saturation Region

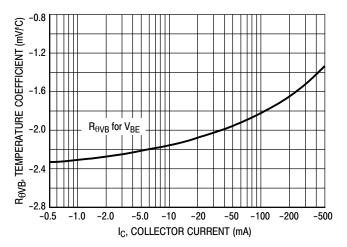
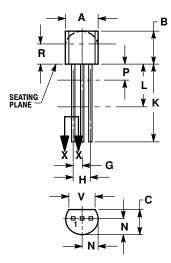


Figure 13. Base-Emitter Temperature Coefficient

#### PACKAGE DIMENSIONS

### TO-92 (TO - 226)CASE 29-11 **ISSUE AL**





#### NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI
- Y14.5M, 1982. CONTROLLING DIMENSION: INCH.
- CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.45	5.20
В	0.170	0.210	4.32	5.33
С	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
G	0.045	0.055	1.15	1.39
Н	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500		12.70	
L	0.250		6.35	
N	0.080	0.105	2.04	2.66
P		0.100		2.54
R	0.115		2.93	
V	0.135		3.43	

STYLE 17: PIN 1. COLLECTOR

BASE

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